

Emergence of Interfacial Polarons from Electron–Phonon Coupling in Graphene/h-BN van der Waals Heterostructures

Chaoyu Chen,[†] José Avila,[†] Shuopei Wang,[‡] Yao Wang,^{§,||,⊥} Marcin Mucha-Kruczyński,^{#,▽} Cheng Shen,[‡] Rong Yang,[‡] Benjamin Nosarzewski,^{§,||} Thomas P. Devereaux,^{||,○} Guangyu Zhang,[‡] and Maria Carmen Asensio^{*,†}

[†]ANTARES Beamline, Synchrotron SOLEIL and Université Paris-Saclay, L'Orme des Merisiers, Saint Aubin-BP 48, 91192 Gif sur Yvette Cedex, France

[‡]Beijing National Laboratory for Condensed Matter Physics and Institute of Physics, Chinese Academy of Sciences, Beijing 100190, China

[§]Department of Applied Physics, Stanford University, California 94305, United States

^{||}Stanford Institute for Materials and Energy Sciences, SLAC National Laboratory and Stanford University, Menlo Park, California 94025, United States

[⊥]Department of Physics, Harvard University, Cambridge, Massachusetts 02138, United States

[#]Department of Physics, University of Bath, Claverton Down, Bath BA2 7AY, United Kingdom

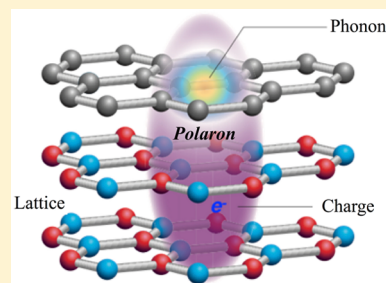
[▽]Centre for Nanoscience and Nanotechnology, University of Bath, Claverton Down, Bath BA2 7AY, United Kingdom

[○]Geballe Laboratory for Advanced Materials, Stanford University, California 94305, United States

Supporting Information

ABSTRACT: van der Waals heterostructures, vertical stacks of layered materials, offer new opportunities for novel quantum phenomena which are absent in their constituent components. Here we report the emergence of polaron quasiparticles at the interface of graphene/hexagonal boron nitride (h-BN) heterostructures. Using nanospot angle-resolved photoemission spectroscopy, we observe zone-corner replicas of h-BN valence band maxima, with energy spacing coincident with the highest phonon energy of the heterostructure, an indication of Fröhlich polaron formation due to forward-scattering electron–phonon coupling. Parabolic fitting of the h-BN bands yields an effective mass enhancement of ~ 2.3 , suggesting an intermediate coupling strength. Our theoretical simulations based on Migdal–Eliashberg theory corroborate the experimental results, allowing the extraction of microscopic physical parameters. Moreover, renormalization of graphene π -band is observed due to the hybridization with the h-BN band. Our work generalizes the polaron study from transition metal oxides to van der Waals heterostructures with higher material flexibility, highlighting interlayer coupling as an extra degree of freedom to explore emergent phenomena.

KEYWORDS: van der Waals heterostructure, NanoARPES, electronic structure, electron–phonon coupling, polaron, Migdal–Eliashberg theory



Van der Waals heterostructures formed by the superposition of two-dimensional (2D) atomic materials have been revealed as a promising field in condensed matter physics.¹ One of the most interesting heterostructures consists of hexagonal boron nitride (h-BN) and monolayer graphene. Their small lattice mismatch ($\sim 1.8\%$) and high interfacial quality have already led to the observation of a number of exotic phenomena such as Hofstadter's butterfly,^{2–4} fractal quantum Hall effect,⁴ and commensurate–incommensurate transition.⁵ Like for most other crystalline materials, it is the intrinsic electronic structure (energy versus momentum relation) that determines their macroscopic behaviors. From the quantum mechanical point of view, electronic bands arise from the overlap of electronic states of atoms in the lattice. Consequently, the electronic structure contains complex

information about the interplay of charge, orbital, spin, and lattice degrees of freedom. For this reason, the electronic structure measurement plays an essential role in understanding the underlying physics of van der Waals heterostructures.

To this point, few techniques to measure the electronic structure of graphene/h-BN vertical heterostructures (G/h-BN) have been employed.^{6–8} Of particular importance is angle-resolved photoemission spectroscopy (ARPES) which measures directly the single-particle spectral function. ARPES studies have revealed the electronic signature of van der

Received: October 30, 2017

Revised: December 24, 2017

Published: January 5, 2018

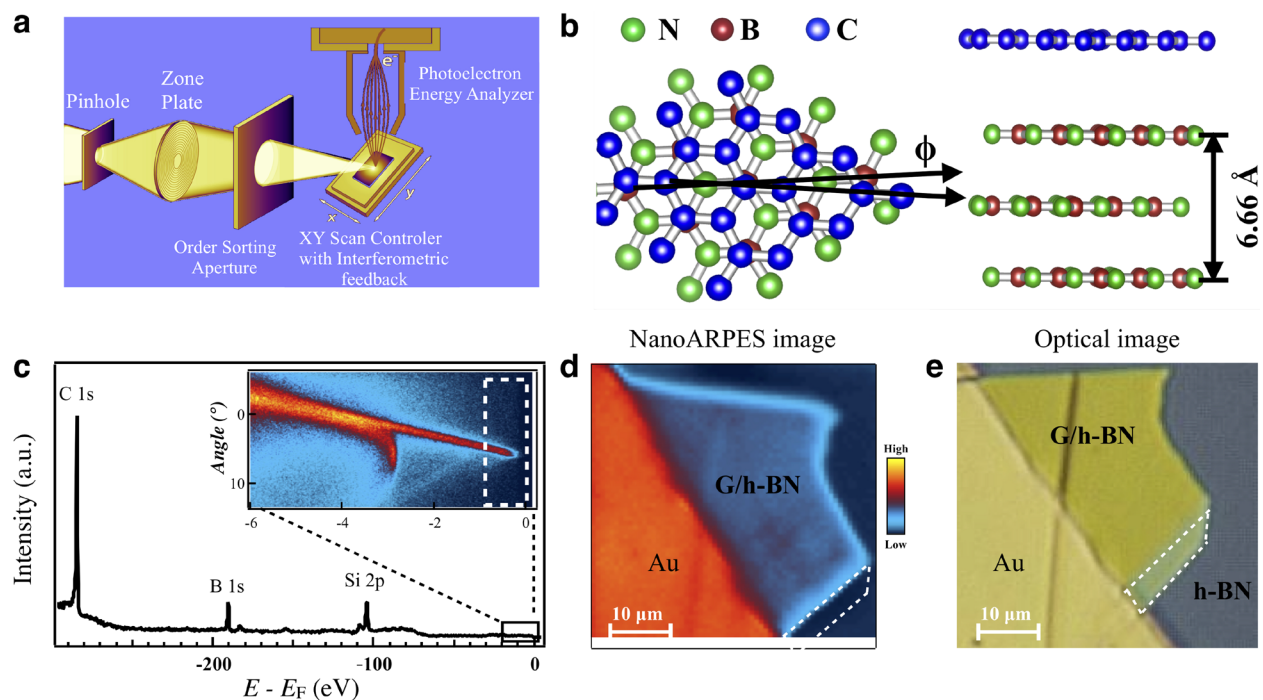


Figure 1. General experimental geometry and sample characterization. (a) Schematic focus mechanism of NanoARPES. (b) Schematic of G/h-BN lattice structure. (c) Overall photoemission core level spectrum taken with beam energy 350 eV and beam spot larger than $50 \mu\text{m}$. The inset shows the detailed NanoARPES spectrum close to Fermi level taken with beam energy 100 eV. (d) NanoARPES image shows the distribution of photoemission intensity integrated from the energy-angle window (dashed box) shown in panel c. (e) Optical image of the measured sample. The heterostructure is grounded by Au contact. Pristine h-BN border is highlighted by dashed white lines in panels d and e.

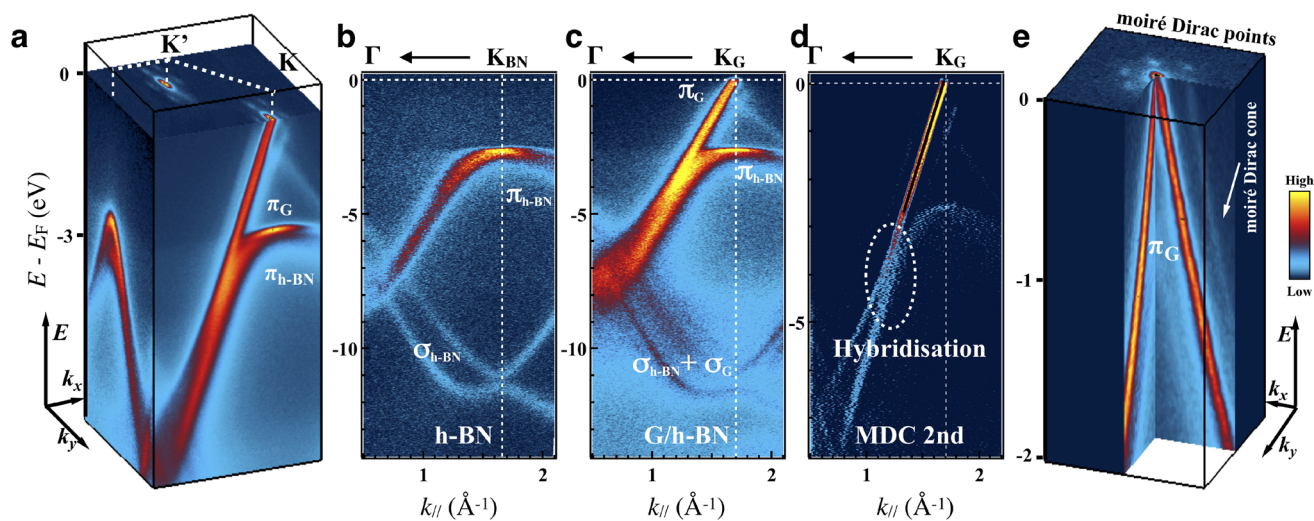


Figure 2. General electronic structure and Fermi surface of G/h-BN heterostructure and pristine h-BN by NanoARPES. (a) Spectral intensity distribution image in (k_x, k_y, E) space for G/h-BN. The top surface shows the Fermi surface. (b,c) NanoARPES band structure along graphene Γ - K direction for pristine h-BN and graphene in G/h-BN. (d) Momentum-distribution-curve-second-derivative (MDC second) spectra along Γ - K direction of graphene in G/h-BN as shown in panel c. The white dashed ellipse indicate the band hybridization region. The black solid line indicates the Dirac cone dispersion. (e) Detailed Dirac cone spectral intensity distribution of G/h-BN in (k_x, k_y, E) space. Again the top surface shows the Fermi surface and emphasizes the existence of moiré Dirac cones.

Waals interaction in G/h-BN.^{6,7} The observed Dirac cone replicas and minigaps are direct consequences of van der Waals potential modulation imposed on graphene. However, surprisingly little is known so far about the modulated electronic structure of h-BN in G/h-BN. Even though the unique electronic, optical, and mechanical properties of graphene in G/h-BN have been well studied, the degree of

disruption of the h-BN band structure at the heterostructure is still an open question.

In this study, we focus on the modulated electronic structure of h-BN in G/h-BN. Currently, high-quality G/h-BN heterostructures, especially those with high device mobility²⁻⁵ are mainly fabricated by transfer method^{9,10} with typical domains in micrometric or nanometric scale. This makes traditional ARPES (spot size $\sim 100 \mu\text{m}$) measurements

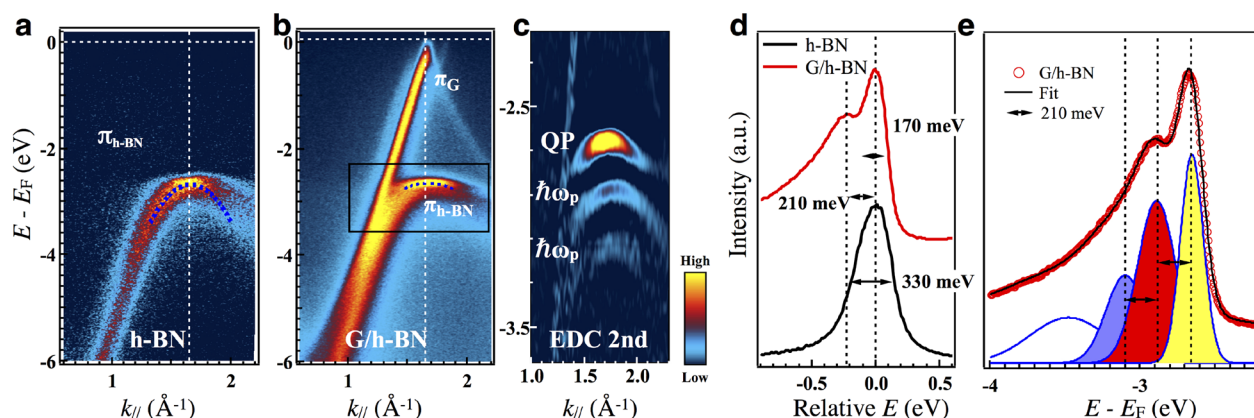


Figure 3. Detailed analysis of Fröhlich polaron spectra of G/h-BN. (a) Valence bands of pristine h-BN along Γ -K direction of h-BN. (b) Valence bands of G/h-BN. Blue dashed lines represent the energy-distribution-curve (EDC)-fitted dispersions. Note that only the Γ -K side is fitted and the K-M side is filled using mirror-plane symmetry. Solid box indicates the region where spectrum in panel c is from. (c) Zoom in EDC second derivative band structure of G/h-BN. (d) Comparison of VBM spectra from pristine h-BN and graphene covered h-BN. Spectra are shifted in energy to be in line with each other. (e) Poisson fitting to the EDC from the K point of G/h-BN.

impossible. To measure G/h-BN with transferred graphene, we employ ARPES with nanometric lateral resolution (Nano-ARPES^{11–13}). From the ARPES E - k spectra, we observe directly renormalization of the graphene Dirac cone where it is close to the h-BN band, probably due to the orbital hybridization between graphene and h-BN, suggesting that orbital character plays a role in shaping the interlayer interaction.¹⁴ More importantly, dispersive replicas of h-BN valence band maxima (VBM) are distinguished at the hexagonal Brillouin zone corner. We attribute these replica bands to the formation of Fröhlich polaron, a composite quasiparticle created in this heterostructure by the coupling of phonons and valence electrons. In particular, we suggest that the characteristic optical zone-center phonons of ~ 210 meV^{15,16} are involved. To extract physical parameters from this polaronic interaction, we calculate the spectral function with Thomas–Fermi screened coupling using Migdal–Eliashberg theory,¹⁷ concluding a rather forward scattering with a characteristic distance of 7 unit cells. The emergence of the Fröhlich polaron in G/h-BN suggests a practical way to create new composite quasiparticles by atomic layer stacking. Controlling the stacking alignment angle¹⁸ or interlayer coupling strength¹⁹ can potentially tune the properties of the quasiparticle. The potential influences on polaron-related physics are also discussed.

NanoARPES principle, sample preparation, and characterization are detailed in [Supplementary Note 1](#). [Figure 1a,b](#) describes the typical NanoARPES setup and sample lattice structure, respectively. The overall photoemission spectra, probed with a beam spot larger than the size of the G/h-BN domain, show sharp core level peaks of carbon 1s, boron 1s, and silicon 2p orbitals, suggesting the absence of hydrocarbon contamination ([Figure 1c](#) and [Supplementary Note 1](#)). The crystallographic alignment angle of graphene with respect to h-BN is defined as $\phi \sim 3^\circ$ as discussed in [Supplementary Note 2](#). [Figure 1d](#) shows the real space map of photoemission intensity (NanoARPES image) around the G/h-BN domain. It was collected by integrating the photoemission signal close to the Fermi level while scanning the sample along two in-plane directions with a focused nanometric beam. This NanoARPES image of the sample matches its optical image with clear contrast ([Figure 1e](#)), demonstrating the capability of our

instrument to identify the sample location of both G/h-BN and h-BN samples precisely with the required lateral resolution and the stability of the whole setup at the submicrometric scale.

Taking advantage of the nanometric sample positioning, Fermi surface and valence band structure of G/h-BN and pristine h-BN are collected, as shown in [Figure 2](#). Although the G/h-BN electronic structure can be naively treated as the superposition of pristine graphene and h-BN valence bands, we observe deviations due to the heterostructure interactions. On the one hand, G/h-BN shares similar h-BN σ - and π -bands with pristine h-BN. This is reflected in the general consistency of $\pi_{\text{h-BN}}$ and $\sigma_{\text{h-BN}}$ between pristine h-BN and G/h-BN (see the comparison in [Figure 2b,c](#)), even with $\sim 3^\circ$ mismatch. Note that because of the insulating nature of the pristine h-BN, its binding energy is calibrated according to our previous work.²⁰ For G/h-BN, electronic states close to the Fermi level are dominated by the monocrystalline graphene π -band, whose Fermi surface consists of only one main set of Dirac points at the Brillouin zone corners. On the other hand, the G/h-BN moiré superlattice, formed due to the lattice mismatch and rotation, imposes periodic potential on graphene and results in Dirac cone replicas ([Figure 2e](#)). This observation is consistent with previous works by atomic force microscopy (AFM) and scanning tunneling microscopy (STM).^{3–5,10,21} Analyzed in detail in [Supplementary Note 2](#), graphene is rotated $\sim 3^\circ$ respect to h-BN and shows no gap opening in the secondary mini Dirac cones.⁷ Furthermore, the graphene Dirac cone and h-BN valence band show signatures of renormalization in the region highlighted in [Figure 2d](#) by the white dashed ellipse, suggesting orbital hybridization between graphene and h-BN. Similar hybridization features have also been observed in graphene/MoS₂ heterostructure.¹⁴ It is believed that only bands with out-of-plane orbital character are responsible for interlayer interaction and modification of the electronic structure. Our findings support this, pointing out the possibility of controlling van der Waals interaction by choosing appropriate materials with different orbital character and twisted angles between them.

We move forward to analyze in detail the h-BN side in order to examine the exotic phenomena induced by van der Waals interaction. As shown in [Figure 3a,b](#), the VBM of pristine h-BN and G/h-BN display significant differences around the K point.

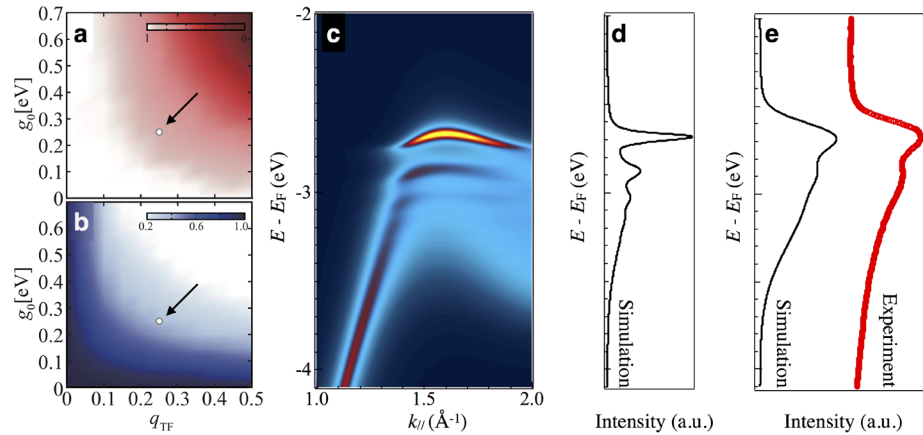


Figure 4. Simulated polaronic spectra of G/h-BN at 100 K by Migdal–Eliashberg theory. (a) Simulated mass enhancement m^*/m_0 and (b) quasiparticle residue $Z_0^{(0)}$ using various coupling strength g_0 and Thomas-Fermi screening wavevector q_{TF} in lattice. The circles indicated by black arrows, denote the optimal parameter ($m^*/m_0 = 2.29$, $Z_0^{(0)} = 0.378$) set compared with experiments. (c) Simulated single-particle spectral function at the optimal parameter set. For simplicity, graphene band is not included. (d) Corresponding simulated EDC though K point with Lorentzian fwhm 40 meV. (e) Comparison between simulation and experiment. The simulated EDC is convolved by a Gaussian peak (~ 150 meV in width).

For pristine h-BN, the VBM consists of a broad parabolic band with a fitted effective mass (only for the Γ - K side) $m_0 \sim 0.6 m_e$ (m_e the free electron mass). This value is in general agreement with previous ARPES works on bulk h-BN²⁰ and quasi-freestanding h-BN on gold.²² In particular, previous NanoARPES work on bulk h-BN²⁰ reported an effective mass $m_0 \sim 0.5 m_e$ in quantitative agreement with our data, especially because in both works by using the same photon energy (100 eV), bands from the same k_z plane are considered. In contrast, for G/h-BN the VBM is much flatter with the effective mass fitted as $m^* \sim 1.4 m_e$. As analyzed in [Supplementary Note 3](#), single-particle model indicates that coupling to graphene increases the VBM effective mass of h-BN. However, this increase is more than 1 order of magnitude too small to explain our experimental observations. This suggests that many-body effects are responsible for the renormalization of the effective mass and it is the construction of heterostructure that induces such change.

To further understand the quasiparticle physics and interactions, we analyze the energy distribution curves (EDCs) at the VBM. As shown in [Figure 3e](#), NanoARPES spectra display additional peaks at multiples of ~ 210 meV below the G/h-BN VBM. A second derivative analysis (see [Figure 3c](#)) proves the existence of multiple parallel replicas. The moiré superlattice reciprocal vector ($0.16 \pm 0.02 \text{ \AA}^{-1}$) is supposed to duplicate the bands along momentum axis and cannot result in such a big energy shift (see [Supplementary Note 4](#) for more detailed discussion). In contrast, the equal energy spacing between these replicas suggests energy shake-off due to electron–phonon coupling (EPC).^{23–27} In addition, the characteristic energy, ~ 210 meV, coincides with the highest frequency of G/h-BN phonons.^{15,16} Note that both graphene and h-BN have phonon frequencies close to this value. Consequently, we cannot identify unambiguously if the phonon involved is from graphene or h-BN. Hence, it is more appropriate to associate these replicas to the heterostructure as a whole.^{15,16} Nevertheless, as discussed in the previous paragraph, the band effective mass enhancement only appears in the heterostructure. That means this EPC is activated with the formation of G/h-BN interface. Therefore, this unique electronic structure represents the interfacial coupling of valence electrons (photoholes) and phonons, resulting in the

emergence of new composite quasiparticles, 2D Fröhlich polarons.

To estimate the coupling strength and fit the polaronic spectra for a preliminary understanding, we follow the same procedure as that employed in previous works.^{23–26} The mass enhancement is estimated as $m^*/m_0 \sim 2.3$, suggesting an intermediate EPC. Assuming zero-momentum phonons for the EPC, the single-particle spectral function follows a Poisson distribution, as shown in [Figure 3e](#) and [Supplementary Note 5](#). This fitting gives the zero-phonon peak intensity fraction of total weight $Z_0^{(0)} \sim 0.34$, corresponding to a 2D Fröhlich coupling constant $\alpha_{2D} \sim 0.9$, according to the diagrammatic quantum Monte Carlo simulation²⁸ and scaling relation.²⁹

To qualitatively explain the polaron formation and its effective mass enhancement, we calculate the spectral function of G/h-BN with a numerical many-body method by introducing a more realistic, finite momentum, forward scattering. The valence bands of h-BN is treated by a tight-binding model with up to third nearest neighbors ([Supplementary Note 6](#)). The coupling between electrons and phonons is described by the Hamiltonian

$$H = \sum_{\mathbf{k}, \sigma} E_{\mathbf{k}} c_{\mathbf{k}\sigma}^\dagger c_{\mathbf{k}\sigma} + \sum_{\mathbf{k}, \mathbf{q}, \sigma} \frac{g(\mathbf{q})}{\sqrt{N}} c_{\mathbf{k}+\mathbf{q}, \sigma}^\dagger c_{\mathbf{k}\sigma} (a_{\mathbf{q}} + a_{-\mathbf{q}}^\dagger) + \Omega_0 \sum_{\mathbf{q}} a_{\mathbf{q}}^\dagger a_{\mathbf{q}} \quad (1)$$

in which the phonon is simulated by a dispersionless Einstein model with energy Ω_0 and $g(\mathbf{q})$ denotes the electron–phonon coupling vertex. We use Migdal–Eliashberg theory to solve the self-energy and Green’s function iteratively ([Supplementary Note 6](#)). This theory has been proven suitable to deal with forward scattering for an intermediate coupling.¹⁷

To capture the screened electron–phonon coupling, we choose a Thomas-Fermi coupling vertex as $g(\mathbf{q}) = 4\pi g_0 (1 + |\mathbf{q}|^2/q_{TF}^2)^{-1}$. Here, q_{TF} presents the Thomas–Fermi screening wavevector, describing the characteristic coupling range in the lattice. In the small q_{TF} limit, this coupling vertex represents the forward scattering, while in the large limit a local Holstein coupling is realized. As shown in [Figure 4a,b](#), with the increase of g_0 and q_{TF} the coupled electron–phonon forms smaller polarons, which is characterized by the effective mass enhancement ([Figure 4a](#)) and quasiparticle residue reduction ([Figure 4b](#)). The physical q_{TF} and coupling strength g_0 are determined through the comparison of experimental effective

mass enhancement and the quasiparticle residue Z_0 . We extract the optimal parameter set $g_0 = 250$ meV and $q_{TF} = 0.25$, at which $m^*/m_0 = 2.29$ and $Z_0 = 0.378$. The optimal screening wave vector reflects a characteristic coupling scale of ~ 7 unit cells. Figure 4c,d shows the simulated spectra function and EDC from K point, respectively. To highlight the weak replicas, we use narrow Lorentzian peaks to simulate the h-BN bands. By convolving with a broader Gaussian peak, the simulated EDC shows satisfactory agreement with the experimental EDC, given the fact that for simulation the background is not included (Figure 4e).

Our findings expand Fröhlich polaron hosts from three-dimensional perovskite surfaces/interfaces^{23–26} to 2D van der Waals heterostructures. It is known that G/h-BN shows enhanced light-matter interaction with unique excitations;³⁰ polarons could potentially interact with these excitations and give rise to an interesting performance of optoelectronic devices.³¹ The large family of 2D materials with diverse band characters allows a flexible approach for exploring polaron physics and its interplay with other emergent phenomena such as excitonic insulator³² and topological insulator.³³ Specifically, 2D transition metal dichalcogenides (TMDCs) TiSe_2 and TiS_2 have shallow conduction bands. Therefore, it is suitable to construct Fröhlich polarons by transferring graphene on top of these materials. Located close to the Fermi level, these polarons will efficiently modify the macroscopic properties of graphene/TMDC heterostructures, providing an excellent platform for studying the interplay of EPC with charge density wave (CDW) and excitonic insulator.³²

Our study suggests interfacial coupling as an extra degree of freedom to develop polaron-related physics. Although interfacial polarons have been observed in $\text{FeSe}/\text{SrTiO}_3$ previously,²³ their formation demands a very delicate epitaxial synthesis environment and no parameter is easily accessible to control the polaronic effect. On the contrary, 2D heterostructures can be fabricated with relatively easier controlled parameters such as alignment angle,^{2,4,5,9,10,18,19} component material,^{14,34} carrier density^{2,4,9,12,34} and so on. This suggests that van der Waals heterostructures are superior to other material systems to serve as a platform for polaron physics study.

■ ASSOCIATED CONTENT

● Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acs.nanolett.7b04604.

Description of NanoARPES, sample preparation and characterization, and charging effect of h-BN; lattice alignment of G/h-BN and Γ point dispersion from NanoARPES measurement; single-particle model of the graphene/h-BN heterostructure; experimental features versus h-BN valence band minibands; Poisson distribution fitting; tight binding model and Migdal-Eliashberg theory (PDF)

■ AUTHOR INFORMATION

Corresponding Author

*E-mail: maria-carmen.asensio@synchrotron-soleil.fr. Phone: 33 (0) 1.69.35.96.69.

ORCID

Chaoyu Chen: 0000-0002-3930-8294

Notes

The authors declare no competing financial interest.

■ ACKNOWLEDGMENTS

The Synchrotron SOLEIL is supported by the Centre National de la Recherche Scientifique (CNRS) and the Commissariat à l'Énergie Atomique et aux Énergies Alternatives (CEA), France. G.Z. thanks the support from the National Basic Research Program of China (973 Program, Grant 2013CB934500), the National Natural Science Foundation of China (NSFC, Grant 61325021). The theoretical work was supported at SLAC and Stanford University by the U.S. Department of Energy, Office of Basic Energy Sciences, Division of Materials Sciences and Engineering, under Contract No. DE-AC02-76SF00515. A portion of the computational work was performed using the resources of the National Energy Research Scientific Computing Center supported by the U.S. Department of Energy, Office of Science, under Contract No. DE-AC02-05CH11231. We thank Professor Shuyun Zhou for inspiring discussions.

■ REFERENCES

- (1) Geim, A. K.; Grigorieva, I. V. *Nature* **2013**, *499*, 419–425.
- (2) Ponomarenko, L. A.; Gorbachev, R. V.; Yu, G. L.; Elias, D. C.; Jalil, R.; Patel, A. A.; Mishchenko, A.; Mayorov, A. S.; Woods, C. R.; Wallbank, J. R.; Mucha-Kruczyński, M.; Piot, B. A.; Potemski, M.; Grigorieva, I. V.; Novoselov, K. S.; Guinea, F.; Fal'ko, V. I.; Geim, A. K. *Nature* **2013**, *497*, 594–597.
- (3) Hunt, B.; Sanchez-Yamagishi, J. D.; Young, A. F.; Yankowitz, M.; LeRoy, B. J.; Watanabe, K.; Taniguchi, T.; Moon, P.; Koshino, M.; Jarillo-Herrero, P.; Ashoori, R. C. *Science* **2013**, *340*, 1427–1430.
- (4) Dean, C. R.; Wang, L.; Maher, P.; Forsythe, C.; Ghahari, F.; Gao, Y.; Katoch, J.; Ishigami, M.; Moon, P.; Koshino, M.; Taniguchi, T.; Watanabe, K.; Shepard, K. L.; Hone, J.; Kim, P. *Nature* **2013**, *497*, 598–602.
- (5) Woods, C. R.; Britnell, L.; Eckmann, A.; Ma, R. S.; Lu, J. C.; Guo, H. M.; Lin, X.; Yu, G. L.; Cao, Y.; Gorbachev, R. V.; Kretinin, A. V.; Park, J.; Ponomarenko, L. A.; Katsnelson, M. I.; Gornostyrev, Y. N.; Watanabe, K.; Taniguchi, T.; Casiraghi, C.; Gao, H. J.; Geim, A. K.; Novoselov, K. S. *Nat. Phys.* **2014**, *10*, 451–456.
- (6) Wang, E.; Lu, X.; Ding, S.; Yao, W.; Yan, M.; Wan, G.; Deng, K.; Wang, S.; Chen, G.; Ma, L.; Jung, J.; Fedorov, A. V.; Zhang, Y.; Zhang, G.; Zhou, S. *Nat. Phys.* **2016**, *12*, 1111–1115.
- (7) Wang, E.; Chen, G.; Wan, G.; Lu, X.; Chen, C.; Avila, J.; Fedorov, A. V.; Zhang, G.; Asensio, M. C.; Zhang, Y.; Zhou, S. *J. Phys.: Condens. Matter* **2016**, *28*, 444002.
- (8) Jobst, J.; van der Torren, A. J.; Krasovskii, E. E.; Balgley, J.; Dean, C. R.; Tromp, R. M.; van der Molen, S. J. *Nat. Commun.* **2016**, *7*, 13621.
- (9) Dean, C. R.; Young, A. F.; Meric, I.; Lee, C.; Wang, L.; Sorgenfrei, S.; Watanabe, K.; Taniguchi, T.; Kim, P.; Shepard, K. L.; Hone, J. *Nat. Nanotechnol.* **2010**, *5*, 722–726.
- (10) Xue, J.; Sanchez-Yamagishi, J.; Bulmash, D.; Jacquod, P.; Deshpande, A.; Watanabe, K.; Taniguchi, T.; Jarillo-Herrero, P.; LeRoy, B. J. *Nat. Mater.* **2011**, *10*, 282–285.
- (11) Avila, J.; Asensio, M. C. *Synchrotron Radiation News* **2014**, *27*, 24–30.
- (12) Chen, C.; Avila, J.; Asensio, M. J. *J. Phys.: Condens. Matter* **2017**, *29*, 183001.
- (13) Chen, C.; Avila, J.; Asensio, M. J. *J. Phys.: Conf. Ser.* **2017**, *849*, 012019.
- (14) Diaz, H. C.; Avila, J.; Chen, C.; Addou, R.; Asensio, M. C.; Batzill, M. *Nano Lett.* **2015**, *15*, 1135–1140.
- (15) Slotman, G. J.; de Wijs, G. A.; Fasolino, A.; Katsnelson, M. I. *Ann. Phys.* **2014**, *526*, 381–386.
- (16) Jung, S.; Park, M.; Park, J.; Jeong, T.-Y.; Kim, H.-J.; Watanabe, K.; Taniguchi, T.; Ha, D. H.; Hwang, C.; Kim, Y.-S. *Sci. Rep.* **2015**, *5*, 16642.

- (17) Wang, Y.; Nakatsukasa, K.; Rademaker, L.; Berlijn, T.; Johnston, S. *Supercond. Sci. Technol.* **2016**, *29*, 054009.
- (18) Woods, C. R.; Withers, F.; Zhu, M. J.; Cao, Y.; Yu, G.; Kozikov, A.; Ben Shalom, M.; Morozov, S. V.; van Wijk, M. M.; Fasolino, A.; Katsnelson, M. I.; Watanabe, K.; Taniguchi, T.; Geim, A. K.; Mishchenko, A.; Novoselov, K. S. *Nat. Commun.* **2016**, *7*, 10800.
- (19) Yankowitz, M.; Watanabe, K.; Taniguchi, T.; San-Jose, P.; LeRoy, B. J. *Nat. Commun.* **2016**, *7*, 13168.
- (20) Henck, H.; Pierucci, D.; Fugallo, G.; Avila, J.; Cassabois, G.; Dappe, Y. J.; Silly, M. G.; Chen, C.; Gil, B.; Gatti, M.; et al. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2017**, *95*, 085410.
- (21) Yang, W.; Chen, G. R.; Shi, Z. W.; Liu, C. C.; Zhang, L. C.; Xie, G. B.; Cheng, M.; Wang, D. M.; Yang, R.; Shi, D. X.; Watanabe, K.; Taniguchi, T.; Yao, Y. G.; Zhang, Y. B.; Zhang, G. Y. *Nat. Mater.* **2013**, *12*, 792–797.
- (22) Usachov, D.; Adamchuk, V. K.; Haberer, D.; Grneis, A.; Sachdev, H.; Preobrajenski, A. B.; Laubschat, C.; Vyalikh, D. V. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2010**, *82*, 075415.
- (23) Lee, J. J.; Schmitt, F. T.; Moore, R. G.; Johnston, S.; Cui, Y. T.; Li, W.; Yi, M.; Liu, Z. K.; Hashimoto, M.; Zhang, Y.; Lu, D. H.; Devereaux, T. P.; Lee, D. H.; Shen, Z. X. *Nature* **2014**, *515*, 245–248.
- (24) Chen, C.; Avila, J.; Frantzeskakis, E.; Levy, A.; Asensio, M. C. *Nat. Commun.* **2015**, *6*, 8585.
- (25) Wang, Z.; McKeown Walker, S.; Tamai, A.; Wang, Y.; Ristic, Z.; Bruno, F. Y.; de la Torre, A.; Riccò, S.; Plumb, N. C.; Shi, M.; Hlawenka, P.; Sánchez-Barriga, J.; Varykhalov, A.; Kim, T. K.; Hoesch, M.; King, P. D. C.; Meevasana, W.; Diebold, U.; Mesot, J.; Moritz, B.; Devereaux, T. P.; Radovic, M.; Baumberger, F. *Nat. Mater.* **2016**, *15*, 835–839.
- (26) Moser, S.; Moreschini, L.; Jaćimović, J.; Barišić, O. S.; Berger, H.; Magrez, A.; Chang, Y. J.; Kim, K. S.; Bostwick, A.; Rotenberg, E.; Forró, L.; Grioni, M. *Phys. Rev. Lett.* **2013**, *110*, 196403.
- (27) Verdi, C.; Caruso, F.; Giustino, F. *Nat. Commun.* **2017**, *8*, 15769.
- (28) Mishchenko, A. S.; Prokof'ev, N. V.; Sakamoto, A.; Svistunov, B. V. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2000**, *62*, 6317–6336.
- (29) Peeters, F. M.; Devreese, J. T. *Phys. Rev. B: Condens. Matter Mater. Phys.* **1987**, *36*, 4442–4445.
- (30) Aggoune, W.; Cocchi, C.; Nabok, D.; Rezouali, K.; Akli Belkhir, M.; Draxl, C. J. *Phys. Chem. Lett.* **2017**, *8*, 1464–1471.
- (31) Withers, F.; del Pozo-Zamudio, O.; Mishchenko, A.; Rooney, A. P.; Gholinia, A.; Watanabe, K.; Taniguchi, T.; Haigh, S. J.; Geim, A. K.; Tartakovskii, A. I.; Novoselov, K. S. *Nat. Mater.* **2015**, *14*, 301–306.
- (32) Cercellier, H.; Monney, C.; Clerc, F.; Battaglia, C.; Despont, L.; Garnier, M. G.; Beck, H.; Aebi, P.; Patthey, L.; Berger, H.; Forro, L. *Phys. Rev. Lett.* **2007**, *99*, 146403.
- (33) Bian, G.; Chung, T.-F.; Chen, C.; Liu, C.; Chang, T.-R.; Wu, T.; Belopolski, I.; Zheng, H.; Xu, S.-Y.; Sanchez, D. S.; Alidoust, N.; Pierce, J.; Quilliams, B.; Barletta, P. P.; Lorcy, S.; Avila, J.; Chang, G.; Lin, H.; Jeng, H.-T.; Asensio, M.-C.; Chen, Y. P.; Hasan, M. Z. *2D Mater.* **2016**, *3*, 021009.
- (34) Diaz, H. C.; Ma, Y.; Kolekar, S.; Avila, J.; Chen, C.; Asensio, M.; Batzill, M. *2D Mater.* **2017**, *4*, 025094.